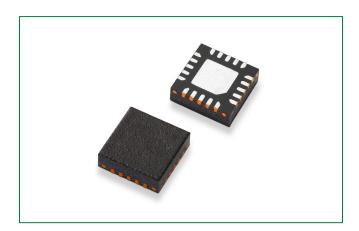
USB Type-C Port CC/SBU Short-to- $V_{\scriptsize BUS}$ Overvoltage Protection

PRELIMINARY & CONFIDENTIAL

Littelfuse, Inc. has characterized initial samples of this device and is currently conducting reliability testing. Parts numbers and specifications are subject to change until the datasheet is made final.

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Pin Description

Pin #	Pin Name	Description
SBU1I	1	Type-C connector side of SBU1 OVP FET. Connect to SBU pin of USB Type-C connector
SBU2I	2	Type-C connector side of SBU2 OVPFET. Connect to SBU pin of USB Type-C connector.
NC	3, 6, 7, 13,16,17, 19, 20	Nothing connected.
CC1I	4	Type-C connector side of CC1 OVP FET. Connect to CC pin of USB Type-C connector.
CC2I	5	Type-C connector side of CC2 OVP FET. Connect to CC pin of USB Type-C connector.
GND	8, 18, EP	Ground connection and thermal pad.
/FLT	9	Open drain fault indictor pin. Pulled down with internal FET when OVP, OTP and fault are detected.
VPWR 10 PD controllers. Bypass VPW		Power supply to the device and external PD controllers. Bypass VPWR to GND with a 1µF ceramic capacitor.
CC2O	11	System side of CC2 OVP FET. Connect to either CC pin of Type-C/PD controller.
CC10	12	System side of CC1 OVP FET. Connect to either CC pin of Type-C/PD controller.
SBU2O	14	System side of SBU2 OVP FET. Connect to either SBU pin of Type-C/PD controller.
SBU10	15	System side of SBU1 OVP FET. Connect to either SBU pin of Type-C/PD controller.

Applications

- USB Type-C Devices
- Notebook
- Desktop
- Monitor
- Industry PC

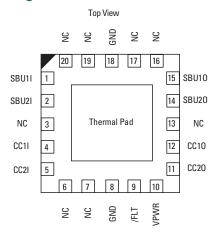
- Point of Sales
- Smart Phone
- Tablet
- Docking Stations

Description

The LS05006VPQ33 is a protection device that helps prevent damage to electronic products with USB Type-C ports. It protects against short circuits, overvoltage up to 24 V, and electrostatic discharge (ESD). Many USB Type-C products don't meet the Type-C specification, and some adapters that only provide 20 V to V_{BUS} can cause short circuits due to pin issues, twisting, or moisture. Without protection, low voltage silicon circuits in Type-C controllers can be damaged. With LS05006VPQ33, downstream low voltage circuits are safeguarded against overvoltage and IEC61000-4-2 ESD strike.

The LS05006VPQ33 has a CC pin pull-down resistor that helps power up and charge mobile devices with dead batteries. Once the system power is up, the device automatically cuts out the CC pin pull-down resistor, allowing the Type-C controller's CC pin pull-down resistor to take over without causing confusion for the power source.

Pinout Designation



Features and Benefits

- Automatically process signals and work transparently without interference or burden on Type-C controller operation.
- Overvoltage protection for 4-channels (CCxI, SBUxI) with 24 V tolerant switch and IEC 61000-4-2 ESD protection.
- Up to 600 mA high current capability for CC1/CC2 overvoltage protection FETs to pass V_{CONN} power.
- Include integrated CC1/CC2 pull-down resistors to handle mobile devices dead battery conditions.
- Designed in a compact package QFN3x3_20L





USB Type-C Port CC/SBU Short-to- $V_{\scriptsize BUS}$ Overvoltage Protection



Absolute Maximum Rating (Reference to GND)

Symbol	Value	Units
VPWR,/FLT	-0.3 to +6	V
CC10,CC20,SBU10,SBU20	-0.3 to +6	V
CC1I,CC2I,SBU1I,SBU2I	-0.3 to +28	V
Lead Temperature (Soldering 10 s)	260	°C
Junction Temperature Range	-40 to +150	°C
Storage Temperature Range	-65 to +150	°C
ESD, Human Body Model (HBM)	±2000	V
IEC61000-4-2 Contact Discharge (CC1, CC2,SBU1, SBU2)	±8000	V

^{*} Notes: Stress exceeding those listed "Absolute Maximum Ratings" may damage the device.

Thermal Information

Symbol	Value	Units
Maximum Power Dissipation ($T_A = 25 ^{\circ}\text{C}$)	1.3	W
Thermal Resistance (θ_{JA})	96	°C/W
Thermal Resistance ($\theta_{_{JC}}$)	44	°C/W

Note1: Measured on JESD51-7, 4-Layer PCB.

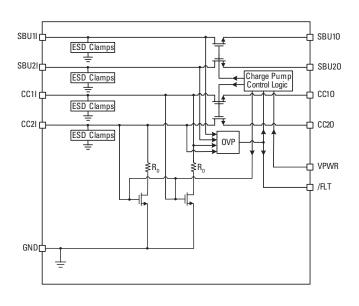
Note 2: The maximum allowable power dissipation is a function of the maximum junction temperature $T_{1,MMN}$ the junction to ambient thermal resistance θ_{JM} and the ambient temperature T_A . The maximum allowable continuous power dissipation at any ambient temperature is calculated by $P_{0,MMN} = \prod_{J,MMN} T_{J}/M_{JM}$. Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.

Recommend Operating Conditions

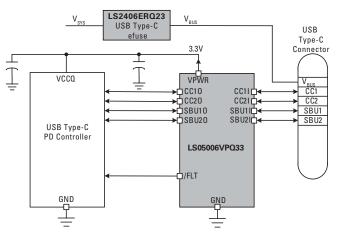
Symbol	Value	Units
CC1I, CC2I, CC1O, CC2O	0 to +5.5	V
SBU1I, SBU2I, SBU1O, SBU2O	0 to +4.3	V
Junction Temperature Range, $T_{_{\rm J}}$	-40 to +125	°C

^{*} Notes: The device is not guaranteed to function outside of the recommended operating conditions.

Functional Block Diagram



Typical Applications





the datasheet is made final. Confidential and proprietary

LS05006VPQ33

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USB Type-C Port CC/SBU Short-to- $V_{\scriptsize BUS}$ Overvoltage Protection

Electrical Characteristics ($T_A = +25$ °C, unless otherwise specified. Typical values are at VPWR = 3.3 V.)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
CC Pin OVP N	MOSFET					
R _{on}		CCxO = 5V, T _J ≤ 105 °C		250		mΩ
R _{ON(FLAT)}	On resistance flatness	Sweep CCxO voltage from 0 V to 1.2 V			5	mΩ
C _{on_cc}	Equivalent on capacitance	Capacitance from CCxI or CCxO to GND when device is powered. $V_{\rm CCxI}$ / $V_{\rm CCxO}$ = 0 V to 1.2 V, f = 400 kHz		50		pF
$R_{_{D}}$	Dead battery pull-down resistance (only present when device is unpowered). Effective resistance of R _D and FET in series	V_CCxI = 2.6 V	4.1	5.1	6.1	kΩ
$V_{\text{TH_DB}}$	Threshold voltage of the pulldown FET in series with $\rm R_{\rm D}$ during dead battery	I_CCxI = 80 μA		0.76		V
V_{OVPCC}	OVP threshold on CCxI pins	Sweep CCxI pin from 5.5 V to 6.5 V until CC FETs turn off.		6.06		V
V _{OVPCC_HYS}	Hysteresis on CCxI OVP	Sweep CCxI pin from 6.5 V to 5.5 V until CC FETs turn on.		85		mV
BW _{on}	On bandwidth single ended (-3 dB)	-3 dB bandwidth from CCxI to CCxO. Single ended measurement, 50Ω system. Vcm = 0.1 V to 1.2 V		100		MHz
$V_{\rm ST_VBUS_CC}$	Short-to-V _{BUS} tolerance on the CCxI pins	Hot plug CCxI pins with a 1 meter USB Type-C Cable. Place a 30 Ω resistor on CCxO pins.			24	V
V _{ST_VBUS_CC_} CLAMP	Short-to-V _{BUS} system-side clamping voltage on the CCxO pins	Hot-Plug CCxI with a 1 meter USB Type-C Cable. Hot-Plug voltage CCxI = 24 V. VPWR = 3.3 V. Place a 30 Ω resistor on CCxO pins.		8		V
BU Pin OVP	MOSFET					
R _{on}		$SBUxO = 3.6 \text{ V}, T_{J} \le 85 ^{\circ}\text{C}$		4		Ω
R _{ON(FLAT)}	On resistance flatness	Sweep SBUxO voltage from 0V to 3.6 V, $-40~{\rm ^{\circ}C} \le T_{\rm J} \le +85~{\rm ^{\circ}C}$		0.7		Ω
C_{on_SBU}	Equivalent on capacitance	Capacitance from SBUxI or SBUxO to GND when device is powered. $V_{\text{SBUx}}IV_{\text{SBUxO}} = 0.3 \text{V to } 3.6 \text{V}.$		11		pF
V_{OVPSBU}	OVP threshold on SBUxI pins	Sweep SBUxl pin from 4 V to 5 V until SBU FETs turn off.		4.5		V
V _{OVPSBU_HYS}	Hysteresis on SBUxl OVP	Sweep SBUxI pin from 5 V to 4 V until SBU FETs turn on.		50		mV
BW _{on}	On bandwidth single ended (-3 dB)	-3 dB bandwidth from SBUxI to SBUxO. Single ended measurement, 50 Ω system. Vcm = 0.1 V to 3.6V		1000		MHz
X_{TALK}	Crosstalk	Measure crosstalk at f = 1 MHz from SBU1O to SBU2I or SBU2O to SBU1I. Vcm1 = 3.6 V, Vcm2 = 0.3 V. Be sure to terminate open sides to 50 Ω .		-80		dB
$V_{\rm ST_VBUS_SBU}$	Short-to-V _{BUS} tolerance on the SBUxI pins	Hot plug SBUxl pins with a 1 meter USB Type-C Cable. Place a 0.1 μ F capacitor in series with a 40 Ω resistor to ground on SBUxO pins.			24	V
V _{ST_VBUS_SBU_}	Short-to-V _{BUS} system-side clamping voltage on the SBUxO pins	Hot Plug SBUxI pins with a 1 meter USB Type-C Cable. Hot-Plug voltage SBUxI = 24 V. VPWR = 3.3 V. Place a 0.15 μ F capacitor in series with a 40 Ω resistor to ground on SBUxO pins.		8		V





LS05006VPQ33USB Type-C Port CC/SBU Short-to-V_{BUS} Overvoltage Protection

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Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
Power Supply	and Leakage Current					
I _{Q_VPWR}	VPWR quiescent current	VPWR = 3.3 V.		120		μΑ
_{CC_LEAK}	Leakage current for CC pins when device is powered.	$\label{eq:VPWR} VPWR = 3.3 \text{ V, } V_{\text{CCxI}} = 3.6 \text{ V, CCxO} \\ \text{pins are floating, measure leakage into CCxI} \\ \text{pins. Result must be same if CCxO side is} \\ \text{biased and CCxI is left floating.}$		4.5		μΑ
I _{SBU_LEAK}	Leakage current for SBU pins when device is powered.	VPWR = 3.3 V, V _{SBUxl} = 3.6 V, SBUxO pins are floating, measure leakage into SBUxl pins. Result must be same if SBUxO side is biased and SBUxl is left floating.		0.1		μА
CCxI_LEAK_OVP	Leakage current for CC pins when device is in OVP	VPWR = 3.3 V, V_{CCxl} = 24 V, CCxO pins are set to 0 V, measure leakage into CCxI pins.		850		μА
CCxO_LEAK_OVP	Leakage current for CC pins when device is in OVP	VPWR = 0 V or 3.3 V, V_{CCxl} = 24 V, CCxO pins are set to 0 V, measure leakage out of CCxO pins.		0.1		μΑ
 SBUXI_LEAK_OVP	Leakage current for SBU pins when device is in OVP	VPWR = 0 V or 3.3 V, V_{SBUxl} = 24 V, SBUxO pins are set to 0 V, measure leakage into SBUxl pins.		400		μА
 SBUXO_LEAK_OVP	Leakage current for SBU pins when device is in OVP	VPWR = 0 V or 3.3 V, V _{SBUxl} = 24 V, SBUxO pins are set to 0 V, measure leakage into SBUxO pins.		0.1		μΑ
VPWR	Input supply range	External Supply Voltage	2.7		5.5	V
V _{UVLO_H}	VPWR under voltage lockout	VPWR Rising		2.40		V
$V_{\text{ULVO_HYS}}$	VPWR UVLO hysteresis	VPWR Falling		-0.2		V
/FLT Pin						
V_{OL}	Low level output voltage	CC pins or SBU pins are in OVP, $I_{\text{JFLT}} = 3 \text{ mA}$, measure the /FLT pin voltage.			0.4	V
t _{OVP_FLT_ASSERTION}	Time from OVP asserted to /FLT pin assertion			36		μs
t _{OVP_FLT_} DEASSERTION	Time from CC FETs turn on after an OVP to /FLT de-assertion			4		ms
Over Temperat	ure Protection					
T _{SD_R}	Thermal shutdown	Rise temperature when /FLT is asserted.		150		°C
T _{SD_HYS}	Thermal shutdown hysteresis	Fall temperature when /FLT is deasserted.		30		°C





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Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
Timing						
t _{ON_FET}	Time from VPWR rise above UVLO until CC and SBU OVP FETs are on	Sweep VPWR from 2 V to 3 V, measure time from UVLO to OVP FETs begin to turn on.		1.3		ms
t _{ON_FET_DB}	Time from crossing rising VPWR UVLO until CC and SBU OVP FETs are on and the dead battery resistors are turned off	Sweep VPWR from 2 V to 3 V, measure time from UVLO to CCxl pins dead battery resistors are disconnected.		4		ms
d _{VPWR_OFF/dt}	Minimum slew rate allowed to guarantee CC and SBU FETs turn off during a power off	VPWR power off. Power off slew rate is 5 V -> 0 V in 10 µs.	-0.5			V/µs
t _{OVP_RESPONSE_CC}	OVP response time on the CC pins. Time from OVP asserted until OVP FETs turn off.	VPWR =3.3 V		70		ns
t _{OVP_RESPONSE_SBU}	OVP response time on the SBU pins. Time from OVP asserted until OVP FETs turn off.	VPWR =3.3 V		80		ns
t _{OVP_RECOVERY_CC_1_FET}	The minimum time duration until the CC FETs turn back on after OVP event. OVP must be removed for CC FETs to turn back on			0.93		ms
tovp_recovery_cc_1_db	The minimum time duration until the CC FETs turn back on and the dead battery resistors turn off. OVP must be removed for CC FETs to turn back on			3.6		ms
tovp_recovery_sbu_1	The minimum time duration until the SBU FETs turn back on. OVP must be removed for SBU FETs to turn back on			0.62		ms
t _{OVP_RECOVERY_CC_2_FET}	Time from OVP removal until CC FETs turn back on, if device has been in OVP > 0.6 ms			0.61		ms
t _{OVP_RECOVERY_CC_2_DB}	Time from OVP removal until CC FETs turn back on and dead battery resistors turn off, if device has been in OVP > 0.6 ms			3.3		ms
t _{OVP_RECOVERY_SBU_2}	OVP recovery time on the SBU pins. Time from OVP removal until SBU FETs turn back on, if device has been in OVP > 0.6 ms			0.3		ms



USB Type-C Port CC/SBU Short-to-V_{BUS} Overvoltage Protection



Detailed Description

The LS05006VPQ33 is a protection solution for USB Type-C ports. It prevents short circuits and electrostatic discharge (ESD) from damaging devices connected to the port. CC and SBU pins are near the V_{BUS} pins in a Type-C connector, which can create a risk of short circuits. To protect devices, these pins need to be 24 V tolerant, even if their operating voltage is lower. LS05006VPQ33 provides 24 V short-to- V_{BUS} overvoltage protection for the CC1, CC2, SBU1, and SBU2 pins of the Type-C port. It also offers IEC 61000-4-2 ESD protection for the CC1I, CC2I, SBU1I, and SBU2I pins.

In a dead battery condition, the system has no power, and VPWR is unavailable. If LS05006VPQ33 is unpowered, the integrated CC pin pull-down resistor will activate, and the pull-up resistor will connect from a power adapter, allowing V_{BUS} voltage. When power is restored, LS05006VPQ33 conducts CC and SBU FETs to establish a handshake with the PD power source, then releases the dead battery resistor in several milliseconds to ensure the CC line pull-down resistor is 5.1 k Ω . Otherwise, the power adapter may interpret this behavior as a port disconnect and remove V_{BUS} voltage.

Application Information

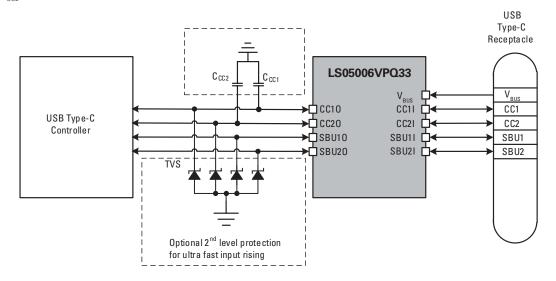
LS05006VPQ33 offers two types of over-voltage protection circuits - passive clamping and active protection. In case of a short circuit between CCxl/SBUxl pins and V_{BUS} , the passive clamping circuit will limit the voltage on CCxO/SBUxO pins, and then within 70 nanoseconds, the active protection circuit will turn off the switch to protect downstream low voltage devices. These circuits provide sufficient protection for downstream devices in most cases.

However, in some cases, a short circuit might occur at the Type-C connector with very low impedance, causing an ultra-fast overvoltage event on CCxI/SBUxI pin that can spike up to 10 V for a very short time. If downstream devices are sensitive to this kind of over-stress, it is recommended to add a second level protection device like a transient voltage suppressor (TVS) with an appropriate trigger voltage on CCxO/SBUxO pins to limit the voltage stress on those pins even with ultra-fast input overvoltage events.

CC Line Capacitance

When USB PD is being used, the total amount of capacitance should be between 200 pF and 600 pF.

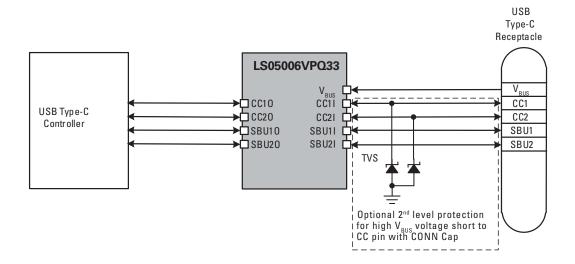
If you connect CC10 to $C_{\rm CC1}$ and CC20 to $C_{\rm CC2'}$, the total capacitance on the CC line is the sum of LS05006VPQ33 CC pin capacitance, the PD controller CC pin capacitance, and $C_{\rm CC1}/C_{\rm CC2}$ capacitance. The LS05006VPQ33 CC pin capacitance is between 43 pF and 65 pF. You should choose the capacitance of $C_{\rm CC1}/C_{\rm CC2}$ based on your PD controller. But the total capacitance, including the CC pin capacitance and the $C_{\rm CC1}/C_{\rm CC2}$ capacitance, should always be between 200 pF and 600 pF.





USB Type-C Port CC/SBU Short-to-V_{BUS} Overvoltage Protection

The CC channel can be used as either a signal channel or a V_{CONN} power channel for the active cable. However, if you use the CC channel as a V_{CONN} power path, there will be a high capacitance on the CCxO pin. This can cause a high transient current during a V_{BUS} to CC short with a long cable, especially when using a high voltage V_{BUS} like 28 V. When the internal passing switching is turned off, this high current and long cable will generate a high voltage spike on the CCxI pin with high energy. This spike could cause internal damage to LS05006VPQ33. To prevent damage to the internal circuit, it's recommended to add a second level protection device like a transient voltage suppressor (TVS) with an appropriate trigger voltage on the CCxI pin in such case of high V_{BUS} voltage and long cable.



Four Channels of Short-to-V $_{\rm BUS}$ Overvoltage Protection (CC1I, CC2I,SBU1I,SBU2I): 24V Tolerant

USB Type-C PD requires a 20 V operation voltage for the V_{BUS} pin, which can swing up to 21 V or 21.5 V during voltage changes. LS05006VPQ33 has four channels of 24 V overvoltage protection for the CC1I, CC2I, SBU1I, and SBU2I pins of the Type-C port. This protection allows for a margin above 21.5 V.

During hot-plugging, a short-to- V_{BUS} event may occur, causing ringing up to twice the settling voltage due to the cable RLC. If the capacitance on the line derates, more than 2x ringing will be seen on the USB Type-C pins during a short-to- V_{BUS} event. To clamp the ringing to approximately 30 V, LS05006VPQ33 has IEC ESD integrated. Additionally, the device integrates 30 V DC tolerant overvoltage protection FETs to handle the ringing during a short-to- V_{BUS} event. Both of these features ensure that LS05006VPQ33 can handle the hotplug ring during a 24 V short-to- V_{BUS} event.

If a short event occurs on the CCxI or SBUxI pin, the overvoltage FETs will quickly turn off to prevent the CCxO and SBUxO pins from seeing high voltage. This effectively protects the PD controller.

Four Channels of IEC 6000-4-2 ESD Protection (CC1I, CC2I,SBU1I,SBU2I)

The V_{BUS}, CC1, CC2, SBU1, and SBU2 from USB Type-C Port are exposed to end-users. System ESD protection is required for devices connected to them due to potential ESD events that could occur when a DC voltage is already applied to these pins. To protect them, a 24 V DC tolerant ESD protection is needed. An LS05006VPQ33 can provide just that, as it integrates four channels of IEC 61000-4-2 ESD protection for CC1I, CC2I, SBU1I, SBU2I pins in a single chip with robust protection even with a 24 V DC voltage applied on those pins.

CC1, CC2 Overvoltage Protection FETs 600 mA Capable for Passing \mathbf{V}_{CONN} Power

The CC pins on the USB Type-C Port can provide power to active cables called V_{CONN} . V_{CONN} voltage ranges from 3 V to 5.5 V and must be able to provide 1 W power, meaning the current ability range is from 200 mA to 333 mA. LS05006VPQ33 includes low Ron overvoltage FETs for CC pins to provide the correct voltage to active cables and can handle large enough current to provide 1 W power.

If in USB PD alternate mode, more power levels are allowed on the V_{CONN} line. LS05006VPQ33 is designed to support up to 600 mA of DC current in addition to the standard 1W required by the USB Type-C specification.



USB Type-C Port CC/SBU Short-to-V_{BUS} Overvoltage Protection



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CC Dead Battery Function for Handling the Dead Battery Case

When the USB Type-C Port is the only power supply for a battery-powered device, the device must be able to charge from the USB Type-C Port, even when the battery is dead. RD pull-down resistors are needed to provide an effective V_{BUS} voltage. These RD pull-down resistors are typically included in a USB Type-C CC/PD controller.

When there is no power provided, LS05006VPQ33 will turn off CC and SBU overvoltage protection FETs to protect the PD controller in the dead battery condition. LS05006VPQ33 integrates high voltage pull-down resistors on CC pins to allow reliable communication between USB PD power source and the device. Once a correct handshake is established, the battery charging can start once the USB PD controller could establish digital communication to the USB PD power source.

When LS05006VPQ33 is in a no-power condition, and the RP pull-up resistor is connected from a power adapter, this RP pull-up resistor activates the RD pull-down resistors inside LS05006VPQ33. When operating in a dead battery condition, CC pins RD pull-down resistors will be exposed, and USB Type-C RP pull-up resistor will activate CC pins resistors firstly, guaranteeing a low voltage V_{BUS} voltage. Once power is restored to the system and back to LS05006VPQ33 on its VPWR pin, CC and SBU overvoltage protection FETs will turn on in a pre-designed delay time. During this period, the USB Type-C Port CC pins will see the RD pull-down resistors of both LS05006VPQ33 and PD controller. The RD pull-down resistors will be disconnected after several milliseconds, avoiding system oscillation and ensuring the PD controller RD is fully exposed before removing the RD of LS05006VPQ33. This sequence helps ensure the USB Type-C source remains attached because a USB Type-C sink must have an RD present on CC pins at all times, according to the USB Type-C spec.

/FLT Pin Assertion

To connect a 100 k Ω resistor between the /FLT pin and VPWR pin, which is important for the LS05006VPQ33, as the /FLT pin is quickly pulled down by an internal MOSFET in just 36 μ s when a fault condition like overvoltage or over temperature occurs. However, once the fault condition is resolved, there is a 4 ms blanking time before the /FLT pin pull down is released.

Soldering Parameters

Average Rar	mp Up Rate (Ts min toT _p)	1~2 °C/second, 3 °C/ second max
	- Temperature Min (T _{s(min)})	150 °C
Preheat & Soak	- Temperature Max (T _{s(max)})	200 °C
Ooak	-Time (min to max) (t _s)	60 - 120 seconds
Time	- Temperature (T _L)	217 °C
Maintained Above	-Time (t _L)	60~150 seconds
Peak Tempe	rature (T _p)	See Classification Temp in table 1
Time within Temperature	5 °C of Actual Peak e (t _p)	30 seconds max
Ramp-down	Rate	6 °C/second max
Time 25 °C 1	to Peak Temperature (T _P)	8 minutes max

Note 1: Tolerance for peak profile temperature (T_p) is defined as a supplier minimum and a user maximum. Note 2: Tolerance for time at peak profile temperature (t_p) is defined as a supplier minimum and a user maximum.

Ordering Information

Part Number	Marking	arking Package Min. Or	
LS05006VPQ33	5006VP	QFN3x3_20L	5000/Tape & Reel

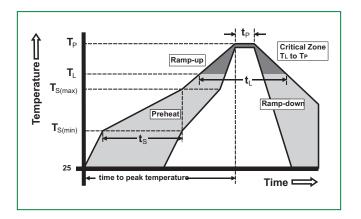


Table 1. Pb-free Process – Classification Temperatures (T_c)

Package Thickness	Volume mm³ <350	Volume mm³ 350-2000	Volume mm³ >2000
<1.6 mm	260 °C	260 °C	260 °C
1.6 mm-2.5 mm	260 °C	250 °C	245 °C
>2.5 mm	250 °C	245 °C	245 °C

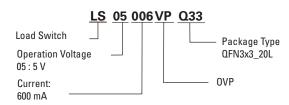
Note: For all temperature information, please refer to topside of the package, measured on the package body surface.



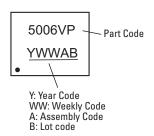
USB Type-C Port CC/SBU Short-to-V_{BUS} Overvoltage Protection



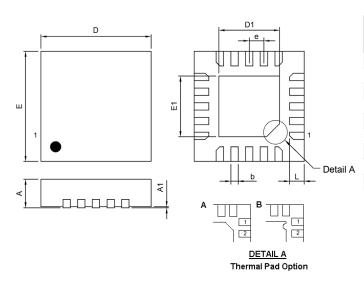
Part Numbering



Part Marking

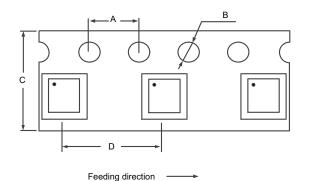


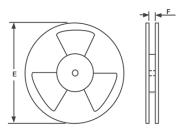
Dimensions - QFN3x3_20L



Dimension	Millin	Millimeters		hes
Dimension	Min	Max	Min	Max
А	0.70	0.80	0.028	0.031
A1	0.00	0.05	0.000	0.002
b	0.20	0.25	0.008	0.010
E	2.90	3.10	0.114	0.122
D	2.90	3.10	0.114	0.122
D1	1.55	1.75	0.061	0.069
E1	1.55	1.75	0.061	0.069
е	0.4	40	0.0	016
L	0.30	0.50	0.012	0.020

Carrier Tape & Reel Specification — QFN3x3_20L





Symbol	Millimeters
Α	4.0
В	1.5
С	12.0
D	8.0
E	13 inch
F	13.0

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